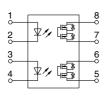


Normally closed type with reinforced insulation

PhotoMOS® GE 2 Form B (AQW414EH)

mm inch



RoHS compliant

FEATURES

- 1. Reinforced insulation of 5,000 V More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).
- 2. Applicable for 2 Form B use as well as two independent 1 Form B use
- **3. Controls low-level analog signals** PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity and high speed response

Can control max. 0.13 A load current with 5 mA input current. Fast operation speed of Typ. 0.8 ms.

5. Low-level off state leakage current

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Electricity, plant equipment
- Security equipment
- Sensing equipment

TYPES

	I/O isolation voltage	Output rating*		Dooksoo	Part No.				Packing quantity	
					Through hole terminal Surface-mount terminal					
		Load Load voltage current	ad Lood	Package		Tape and reel		packing style		Tape and reel
				Tube packing style		Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Tube		
AC/DC dual use	Reinforced 5,000 Vrms	400 V	100 mA	DIP8-pin	AQW414EH	AQW414EHA	AQW414EHAX	AQW414EHAZ	1 tube contains : 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

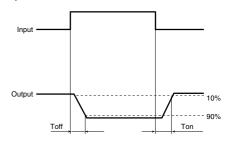
Item		Symbol	AQW414EH(A)	Remarks	
Input	LED forward current	l _F	50mA		
	LED reverse voltage	VR	5V		
	Peak forward current	IFP	1A	f =100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin	75mW		
Output	Load voltage (peak AC)	VL	400 V		
	Continuous load current	IL	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1 channel.	
	Peak load current	Ipeak	0.3 A	100 ms (1 shot), V _L = DC	
	Power dissipation	Pout	800mW		
Total power dissipation		PT	850mW		
I/O isolation voltage		Viso	5,000 Vrms		
Ambient	Operating	Topr	-40 to +85°C −40 to +185°F	(Non-icing at low temperatures)	
temperat	ture Storage	T _{stg}	-40 to +100°C −40 to +212°F		

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2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item		Symbol AQW414EH(A)		Condition	
Input	LED operate (OFF) current	Typical	- I Foff	1.3mA	IL=Max.	
	LED operate (OFF) current	Maximum	IF-off	3.0mA	IL=IVIAX.	
	LED reverse (ON) current	Minimum	- IFon	0.4mA	IL=Max.	
	LED reverse (ON) current	Typical	IFon	1.2mA	IL=IVIAX.	
	LED dropout voltage	Typical	VF	1.25 (1.14 V at I⊧=5mA)	I=50mA	
	LED dropout voltage	Maximum	VF	1.5V	IF=50IIIA	
Output		Typical		26Ω	I _F =0mA	
	On resistance	Maximum	Ron	35Ω	I∟=Max. Within 1 s	
	Off state leakage current	Maximum	ILeak	10μΑ	I _F =5mA V _L =Max.	
	Operate (OFF) time*	Typical	- T _{off}	0.8ms	I⊧=0mA→5mA	
	Operate (OFF) time	Maximum	I off	3.0ms	I∟=Max.	
	Reverse (ON) time*	Typical	- T _{on}	0.2ms	I⊧=5mA→0mA	
Transfer characteristics	neverse (ON) time	Maximum	Ion	1.0ms	I∟=Max.	
	I/O sanasitanas	Typical		0.8pF	f =1MHz	
	I/O capacitance	Maximum	Ciso	1.5pF	V _B =0V	
	Initial I/O isolation resistance	Minimum	Riso	1,000ΜΩ	500V DC	

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

	Item	Symbol	Number of used channels	Min.	Max.	Unit
L	ED current	lF		5	30	mA
	Load voltage (Peak AC)	V∟		_	320	V
AQW414EH(A)	Continuous load current	lL	1ch 2ch	_	0.13 0.1	Α

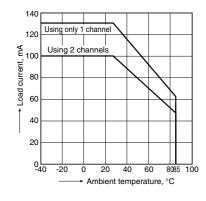
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

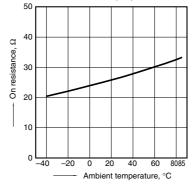
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C



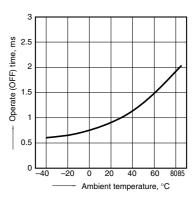
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 0 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



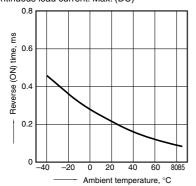
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



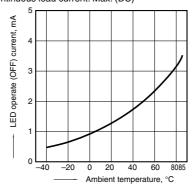
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

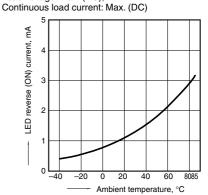


5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: Max. (DC);

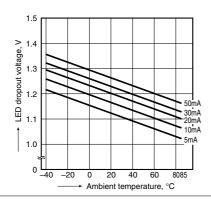
Continuous load current: Max. (DC)



6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: Max. (DC);

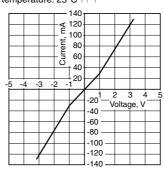


7. LED dropout voltage vs. ambient temperature characteristics; LED current: 5 to 50 mA



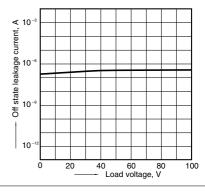
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 7



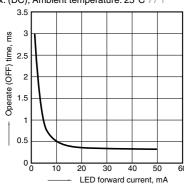
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



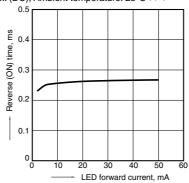
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77



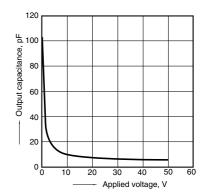
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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